Electronic Supplementary Material (ESI) for Journal of Materials Chemistry A. This journal is © The Royal Society of Chemistry 2014

## Supporting Information

**Title** Solution-Processed Barium Hydroxide Modified Al doped Zinc Oxide Layer for Highly Efficient Inverted Organic Solar Cells

Hong Zhang, Tobias Stubhan, Ning Li, Mathieu Turbiez, Gebhard J. Matt, Tayebeh Ameri, and Christoph J. Brabec



Figure S1. *j*-V characteristics of typical devices with different concentrations of Ba(OH)<sub>2</sub>.



Figure S2. Photovoltaic parameters distribution of over 6 solar cells; the boxes represent the 25-75% distribution range, and hollow squares represent the mean values (WO = without Ba(OH)<sub>2</sub> and W = with Ba(OH)<sub>2</sub>).



Figure S3. a) j-V characteristics of inverted pDPP5T-2:PC<sub>61</sub>BM organic solar cells without and with the Ba(OH)<sub>2</sub> layer on TiO<sub>2</sub> layer. b) Corresponding logarithmic plot of dark j-V characteristics.

Table S1. Key values of the *j*-*V* characteristics of inverted pDPP5T-2:PC<sub>61</sub>BM organic solar cells without and with the Ba(OH)<sub>2</sub> layer on TiO<sub>2</sub> layer.

iOSCs (pDPP5T-	$V_{OC}$	$J_{SC}$	FF	PCE	$R_{\rm S}$	$R_{ m Sh}$			
2:PC <sub>61</sub> BM)	(V)	(mA cm <sup>-2</sup> )	(%)	(%)	$(\Omega \text{ cm}^2)$	$(k\Omega \ cm^2)$			
Without Ba(OH) <sub>2</sub>	0.54	-12.00	54.00	3.50	2.47	5.16			
With Ba(OH) <sub>2</sub>	0.56	-15.02	63.18	5.32	0.64	552.79			



Figure S4. Surface topographic AFM images (size:  $2.5 \times 2.5 \,\mu\text{m}^2$ ) of (a) bare AZO layer, (b) thin Ba(OH)<sub>2</sub> on the AZO layer, (c) pDPP5T-2:PC<sub>61</sub>BM BHJ film on the AZO layer without Ba(OH)<sub>2</sub> inserted and (d) (c) pDPP5T-2:PC<sub>61</sub>BM BHJ film on the AZO layer with Ba(OH)<sub>2</sub> inserted.



Figure S5. Semilog plot of dark *j*-*V* characteristics curves of inverted organic solar cells without and with the  $Ba(OH)_2$  layer .The dashed lines show the extrapolated line for determining saturation current density from intercept and diode ideality factor from the slope.



Figure S6. The box chats is obtained from j-V fitting on 12 electron-only devices without and with the Ba(OH)<sub>2</sub> layer.

The solid lines represent the fit using the SCLC model as given in the following Equation,

$$J_{SCL} = \frac{9}{8} \varepsilon_0 \varepsilon_r \mu \frac{V^2}{L^3}$$

where  $J_{SCL}$  is the current density,  $\mu$  is the effective charge carrier mobility,  $\varepsilon_0$  the permittivity of free space,  $\varepsilon_r$  is the the dielectric permittivity of the active layer, V is the applied voltage, and L is the thickness of the active layer.



(a)

Figure S7. a) j-V characteristics of inverted P3HT:PC<sub>61</sub>BM organic solar cells without and with the Ba(OH)<sub>2</sub> layer. b) Corresponding logarithmic plot of dark j-V characteristics.

Table S2. Key values of the *j*-*V* characteristics of inverted P3HT:PC<sub>61</sub>BM organic solar cells without and with the Ba(OH)<sub>2</sub> layer.

iOSCs	$V_{OC}$	$J_{SC}$	FF	PCE	R <sub>S</sub>	$R_{ m Sh}$
(P3HT:PC <sub>61</sub> BM)	(V)	(mA cm <sup>-2</sup> )	(%)	(%)	$(\Omega \text{ cm}^2)$	$(k\Omega \ cm^2)$
Without Ba(OH) <sub>2</sub>	0.54	-7.50	60.51	2.45	0.85	16.19
With Ba(OH) <sub>2</sub>	0.56	-8.03	66.20	2.98	0.74	45.54

6